## **DISCRETE SEMICONDUCTORS**

# DATA SHEET

# **PDTC114E series** NPN resistor-equipped transistor; R1 = 10 kΩ, R2 = 10 kΩ

Product data sheet Supersedes data of 2003 Apr 10 2004 Aug 05



# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

#### **FEATURES**

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

### **APPLICATIONS**

- General purpose switching and amplification
- · Inverter and interface circuits
- Circuit driver.

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
$V_{CEO}$	collector-emitter voltage	_	50	V
Io	output current (DC)	_	100	mA
R1	bias resistor	10	_	kΩ
R2	bias resistor	10	_	kΩ

### **DESCRIPTION**

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

#### **PRODUCT OVERVIEW**

TVDE NUMBER	PAC	KAGE	MARKING CODE	DND COMPLEMENT
TYPE NUMBER	PHILIPS EIAJ		MARKING CODE	PNP COMPLEMENT
PDTC114EE	SOT416	SC-75	09	PDTA114EE
PDTC114EEF	SOT490	SC-89	09	PDTA114EEF
PDTC114EK	SOT346	SC-59	04	PDTA114EK
PDTC114EM	SOT883	SC-101	DS	PDTA114EM
PDTC114ES	SOT54 (TO-92)	SC-43	TC114E	PDTA114ES
PDTC114ET	SOT23	_	*16 <sup>(1)</sup>	PDTA114ET
PDTC114EU	SOT323	SC-70	*09 <sup>(1)</sup>	PDTA114EU

### Note

<sup>1. \* =</sup> p: Made in Hong Kong.

<sup>\* =</sup> t: Made in Malaysia.

<sup>\* =</sup> W: Made in China.

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# PDTC114E series

## SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	CIMPLIFIED OUTLINE AND CYMPOL		PINNING
TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PIN	DESCRIPTION
PDTC114ES		1	base
		2	collector
	R1 R1 R2 R2 R2 R2 R2	3	emitter
PDTC114EE PDTC114EF PDTC114EK PDTC114ET PDTC114EU	Top view  1 R1 3 R2 2 MDB269	1 2 3	base emitter collector
PDTC114EM	2 R1 3 Bottom view MHC506	1 2 3	base emitter collector

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V
VI	input voltage				
	positive		_	+40	V
	negative		_	-10	V
Io	output current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		_	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	_	200	mW
	SOT416	note 1	_	150	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W
	SOT883	notes 2 and 3	500	K/W

#### **Notes**

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# PDTC114E series

### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0	_	_	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; I_{B} = 0$	_	_	1	μΑ
		V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0; T <sub>j</sub> = 150 °C	_	_	50	μА
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0$	_	_	400	μА
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 5 mA	30	_	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	_	_	150	mV
$V_{i(off)}$	input-off voltage	$I_C = 100 \mu A; V_{CE} = 5 V$	_	1.1	0.8	V
V <sub>i(on)</sub>	input-on voltage	$I_C = 10 \text{ mA}; V_{CE} = 0.3 \text{ V}$	2.5	1.8	-	V
R1	input resistor		7	10	13	kΩ
R2 R1	resistor ratio		0.8	1	1.2	
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = 10 \text{ V}$ ; $f = 1 \text{ MHz}$	_	_	2.5	pF

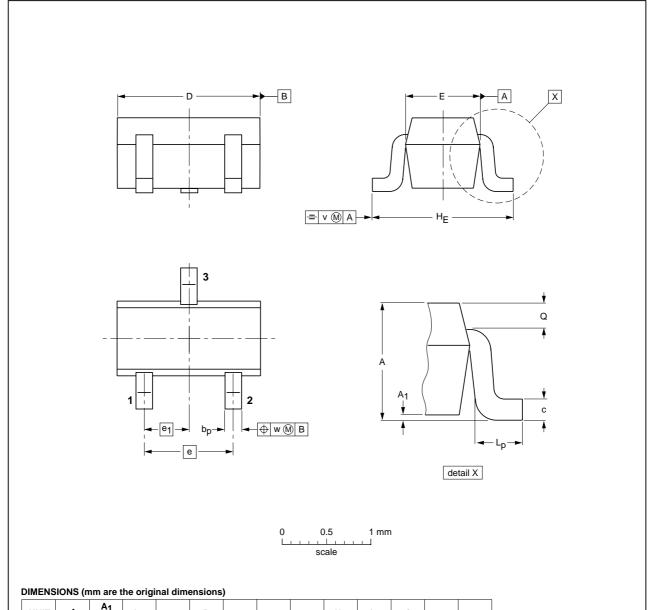
# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

### **PACKAGE OUTLINES**

Plastic surface-mounted package; 3 leads

SOT416



UNIT	Α	A <sub>1</sub> max	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	ø	v	w
mm	0.95 0.60	0.1	0.30 0.15	0.25 0.10	1.8 1.4	0.9 0.7	1	0.5	1.75 1.45	0.45 0.15	0.23 0.13	0.2	0.2

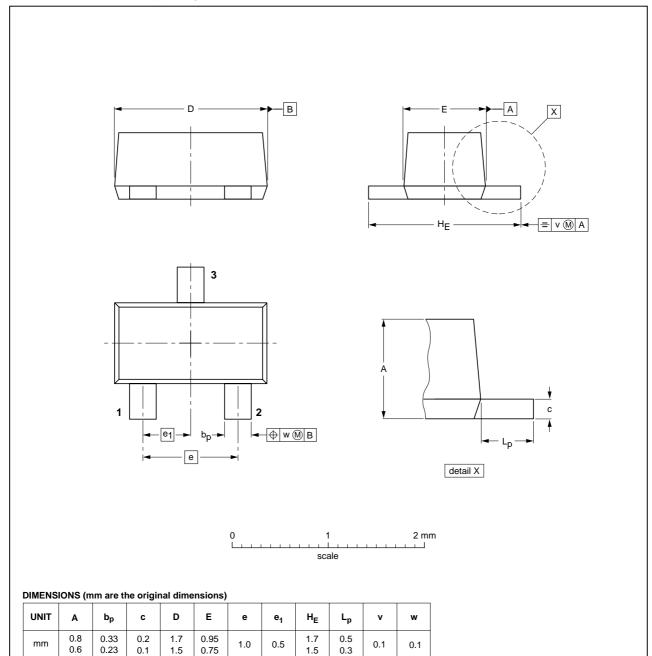
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT416			SC-75			<del>04-11-04</del> 06-03-16

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

# PDTC114E series

### Plastic surface-mounted package; 3 leads

SOT490



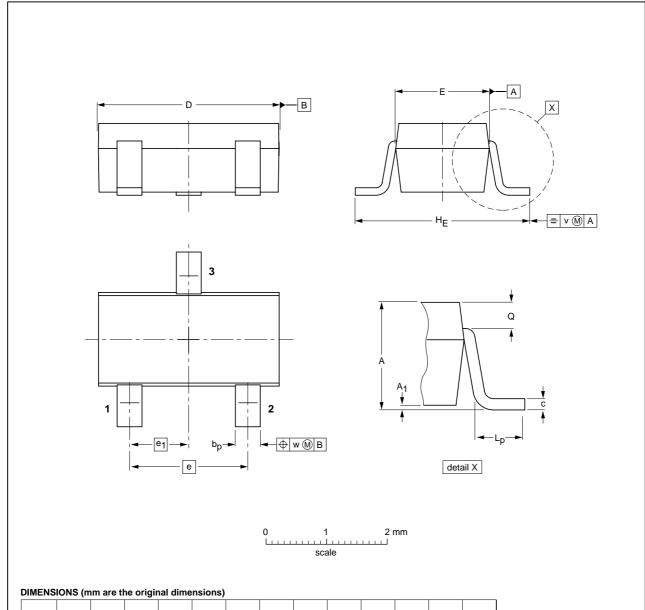
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VERSION	IEC	JEDEC JEITA PROJEC		PROJECTION	ISSUE DATE	
SOT490			SC-89			<del>05-07-28</del> 06-03-16

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

### Plastic surface-mounted package; 3 leads

SOT346



UNIT	Α	A <sub>1</sub>	bp	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	v	w
mm	1.3 1.0	0.1 0.013	0.50 0.35	0.26 0.10	3.1 2.7	1.7 1.3	1.9	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2

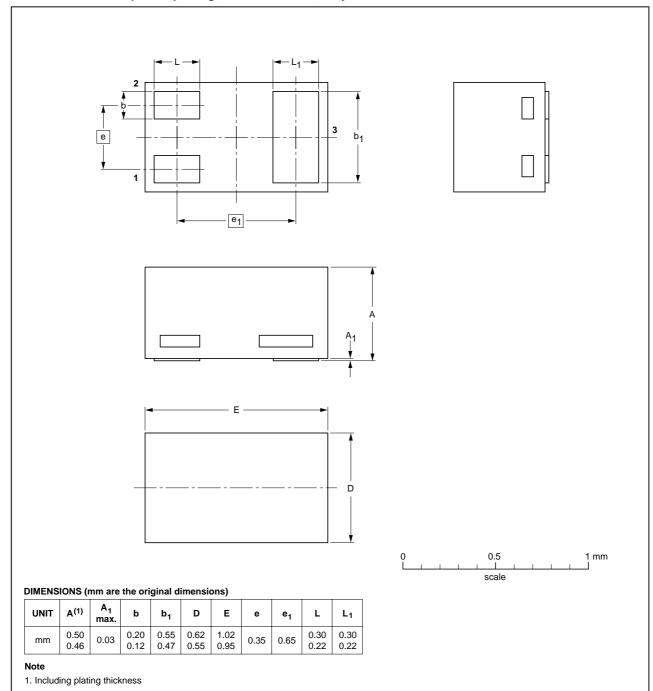
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT346		TO-236	SC-59A			<del>04-11-11</del> 06-03-16	

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

### Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

**SOT883** 



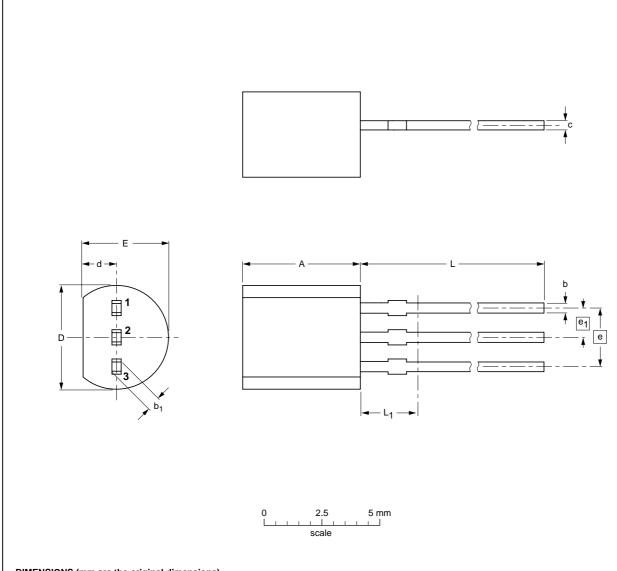
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	1990E DATE	
SOT883			SC-101			<del>03-02-05</del> 03-04-03	

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

### Plastic single-ended leaded (through hole) package; 3 leads

SOT54



### **DIMENSIONS** (mm are the original dimensions)

UNIT	Α	b	b <sub>1</sub>	С	D	d	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup> max.	
mm	5.2 5.0	0.48 0.40	0.66 0.55	0.45 0.38	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5	

#### Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

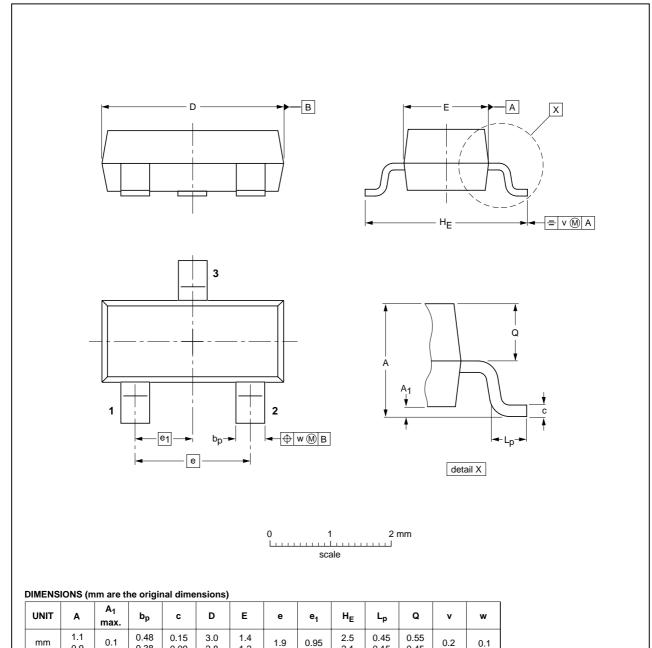
OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT54		TO-92	SC-43A			<del>-04-06-28</del> 04-11-16

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

### Plastic surface-mounted package; 3 leads

SOT23



OUTLINE		REFER	EUROPEAN	IOOUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>-04-11-04-</del> 06-03-16

2004 Aug 05 11

0.38

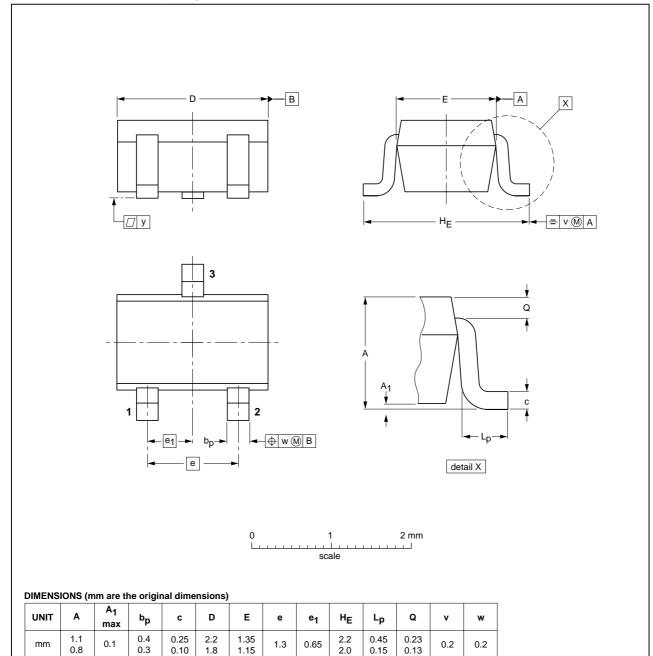
0.9

# NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

## PDTC114E series

### Plastic surface-mounted package; 3 leads

**SOT323** 



OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	
SOT323			SC-70		<del>04-11-04</del> 06-03-16

## NPN resistor-equipped transistor; R1 = 10 k $\Omega$ , R2 = 10 k $\Omega$

### PDTC114E series

#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

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#### **Contact information**

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